

PJA138K-AU

50V N-Channel Enhancement Mode MOSFET – ESD Protected

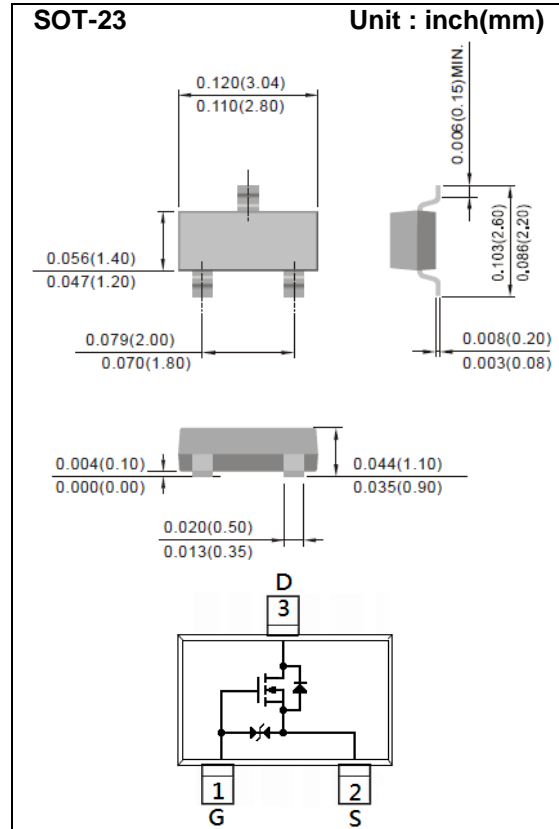
Voltage **50 V** **Current** **500mA**

Features

- RDS(ON) , V_{GS}@10V, I_D@500mA<1.6Ω
- RDS(ON) , V_{GS}@4.5V, I_D@200mA<2.5Ω
- RDS(ON) , V_{GS}@2.5V, I_D@100mA<4.5Ω
- Advanced Trench Process Technology.
- Specially Designed for Battery Operated Systems, Solid-State Relays Drivers: Relay, Displays, Memories, etc.
- AEC-Q101 qualified.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS |
|--|----------------------|-----------------------------------|---------|-------|
| Drain-Source Voltage | | V _{DS} | 50 | V |
| Gate-Source Voltage | | V _{GS} | +20 | V |
| Continuous Drain Current | | I _D | 500 | mA |
| Pulsed Drain Current | | I _{DM} | 1200 | mA |
| Power Dissipation | T _A =25°C | P _D | 500 | mW |
| | Derate above 25°C | | 4 | mW/°C |
| Operating Junction and Storage Temperature Range | | T _J , T _{STG} | -55~150 | °C |
| Typical Thermal Resistance | | R _{θJA} | 250 | °C/W |
| - Junction to Ambient (Note 3) | | | | |

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Electrical Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|---|---------------------|--|------|------|------|-------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250uA | 50 | - | - | V |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250uA | 0.8 | 1.0 | 1.5 | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =10V, I _D =500mA | - | 0.96 | 1.6 | Ω |
| | | V _{GS} =4.5V, I _D =200mA | - | 1.25 | 2.5 | |
| | | V _{GS} =2.5V, I _D =100mA | - | 2.73 | 4.5 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =50V, V _{GS} =0V | - | 0.01 | 1 | uA |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} =±20V, V _{DS} =0V | - | ±3.0 | ±10 | |
| Dynamic (Note 4) | | | | | | |
| Total Gate Charge | Q _g | V _{DS} =25V, I _D =250mA, V _{GS} =4.5V (Note 1,2) | - | 0.63 | 1 | nC |
| Gate-Source Charge | Q _{gs} | | - | 0.2 | - | |
| Gate-Drain Charge | Q _{gd} | | - | 0.23 | - | |
| Input Capacitance | C _{iss} | V _{DS} =25V, V _{GS} =0V, f=1.0MHZ | - | 25 | 50 | pF |
| Output Capacitance | C _{oss} | | - | 9.5 | 20 | |
| Reverse Transfer Capacitance | C _{rss} | | - | 2.1 | 5 | |
| Turn-On Delay Time | t _{d(on)} | V _{DD} =25V, I _D =500mA, V _{GS} =10V, R _G =6Ω (Note 1,2) | - | 2.2 | 5 | ns |
| Turn-On Rise Time | t _r | | - | 19.2 | 38 | |
| Turn-Off Delay Time | t _{d(off)} | | - | 6.2 | 12 | |
| Turn-Off Fall Time | t _f | | - | 23 | 50 | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source Diode Forward Current | I _S | --- | - | - | 500 | mA |
| Diode Forward Voltage | V _{SD} | I _S =500mA, V _{GS} =0V | - | 0.86 | 1.5 | V |

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%
2. Essentially independent of operating temperature typical characteristics.
3. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper
4. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

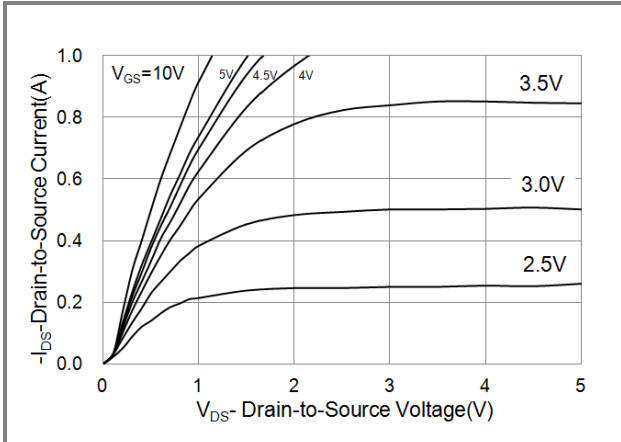


Fig.1 On-Region Characteristics

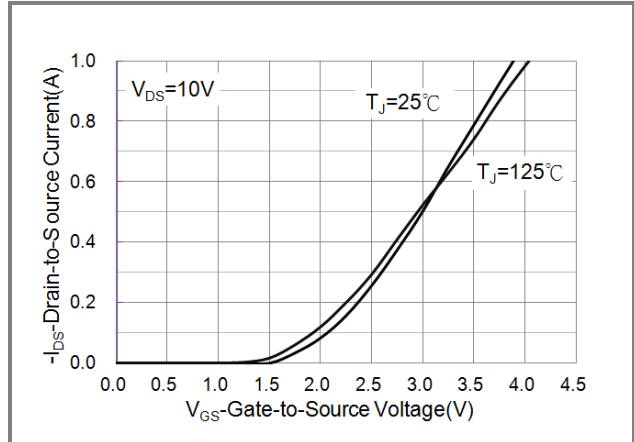


Fig.2 Transfer Characteristics

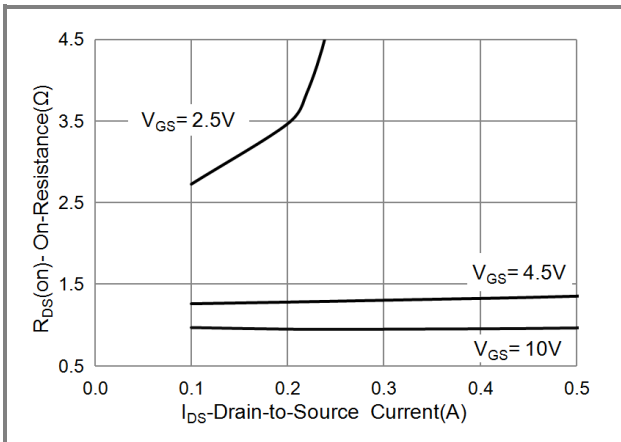


Fig.3 On-Resistance vs. Drain Current

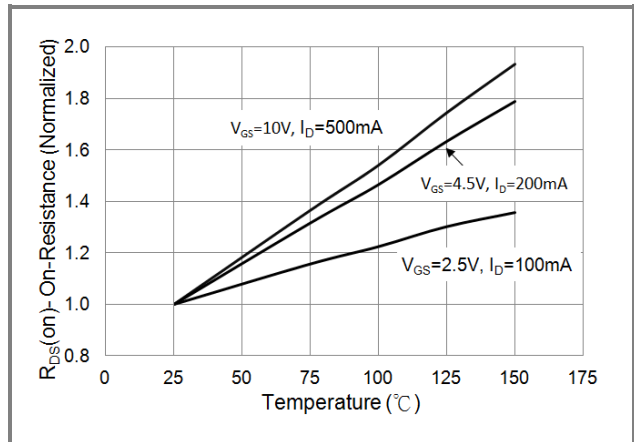


Fig.4 On-Resistance vs. Junction temperature

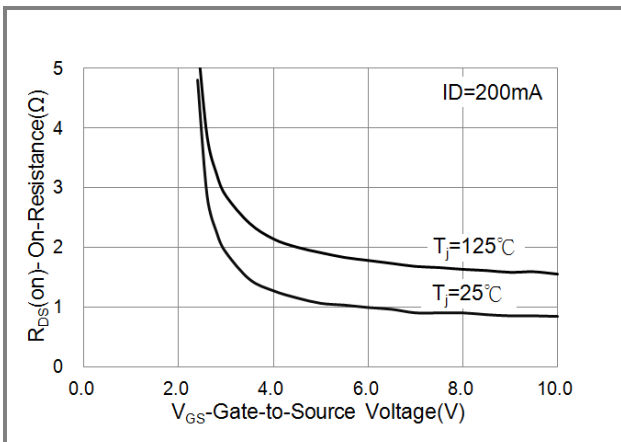


Fig.5 On-Resistance Variation with VGS.

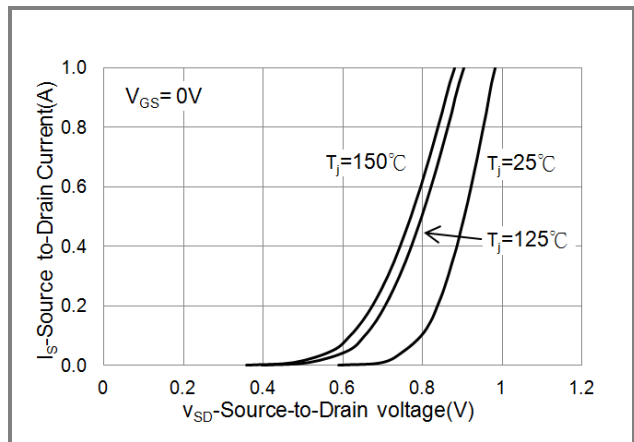


Fig.6 Body Diode Characteristics

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TYPICAL CHARACTERISTIC CURVES

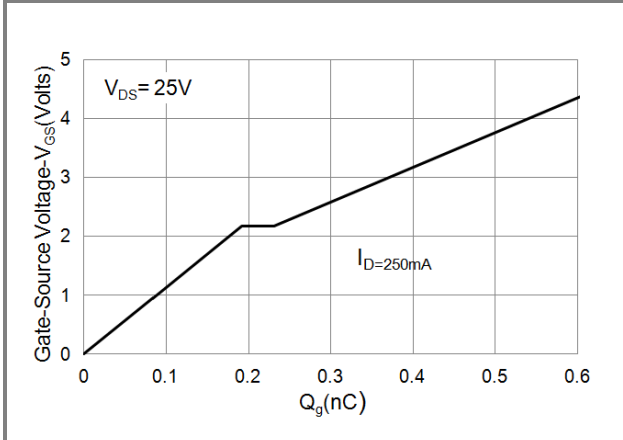


Fig.7 Gate-Charge Characteristics

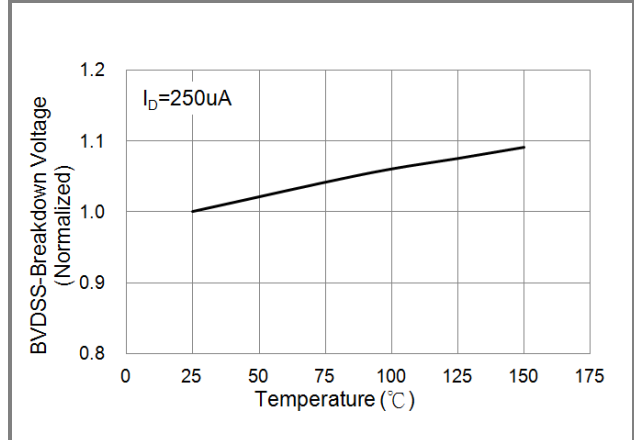


Fig.8 Breakdown Voltage Variation vs. Temperature

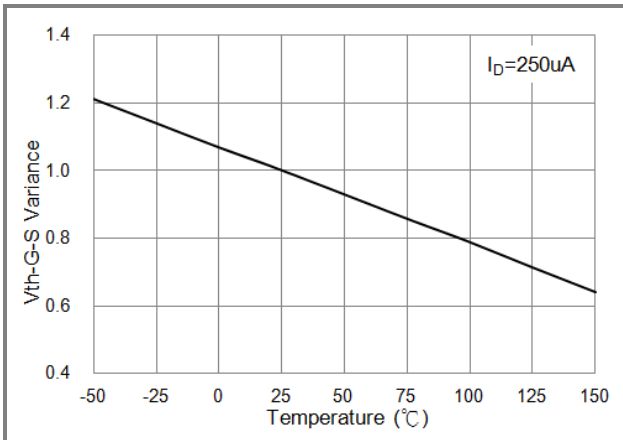


Fig.9 Threshold Voltage Variation with Temperature.

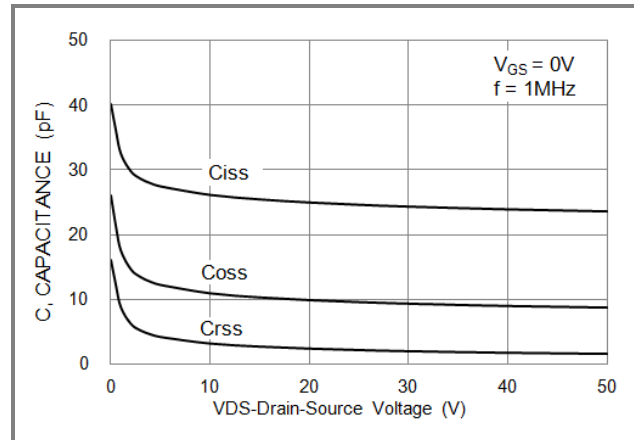


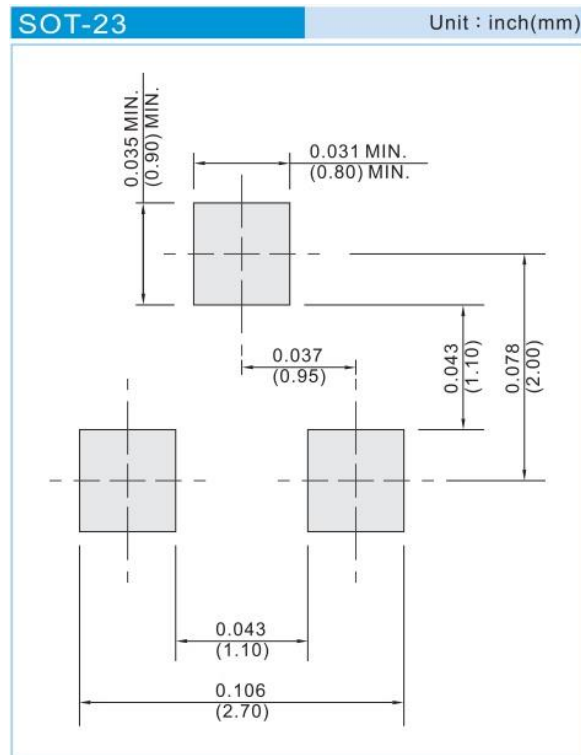
Fig.10 Capacitance vs. Drain-Source Voltage.

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Product and Packing Information

| Part No. | Package Type | Packing Type | Marking |
|------------|--------------|------------------|---------|
| PJA138K-AU | SOT-23 | 3K pcs / 7" reel | 8K3 |

Mounting Pad Layout



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